

INCHANGE SEMICONDUCTOR

Isc N-Channel MOSFET Transistor

IXTY44N10T

• FEATURES

- With To-252(DPAK) package
- · Low input capacitance and gate charge
- · Low gate input resistance
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

Switching applications

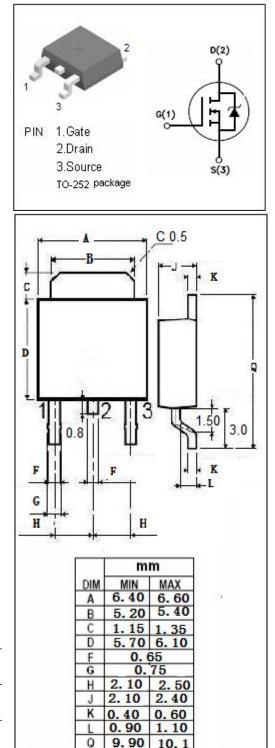
• ABSOLUTE MAXIMUM RATINGS(Ta=25 C)							
SYMBOL	PARAMETER	VALUE	UNIT				
V _{DSS}	Drain-Source Voltage	100	V				
V _{GSS}	Gate-Source Voltage	±30	V				
ID	Drain Current-ContinuousTc=25℃ Tc=100℃	44 25	A				
I _{DM}	Drain Current-Single Pulsed	140	А				
PD	Total Dissipation @Tc=25°C	130	W				
Tj	Max. Operating Junction Temperature	175	°C				
T _{stg}	Storage Temperature	-55~175	°C				

• ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	1.15	°C/W	
Rth(ch-a)	Channel-to-ambient thermal resistance	55	°C/W	

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ELECTRICAL CHARACTERISTICS

$T_{C}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	100			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = ±30V; I _D =0.25mA	2.5		4.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =22A		22	30	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} =0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} =100V; V _{GS} = 0V;Tj=25℃ Tj=150℃			1 100	μA
V _{SDF}	Diode forward voltage	I _{SD} =25A, V _{GS} = 0 V			1.1	V

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